

Technical drawing showing the side profile of the device. Dimensions are indicated:

- Height from mounting surface to top edge: 1,5"
- Maximum height of the central component: max 14
- Maximum height of the rightmost component: max 17

A schematic cross-section of a device. It features a central rectangular block with a smaller rectangle on top. Below the central block is a cross-hatched base. Two curved lines, representing contacts or leads, extend from the sides of the central block to the base. Each contact is labeled with a circled 'n.5' and an arrow pointing to it.

A schematic diagram of a three-layer system. A central rectangular layer is flanked by two thinner rectangular layers. All three layers sit on a cross-hatched substrate. Two arrows, each labeled 'n.5' in a circle, point vertically downwards towards the top surfaces of the two outer layers, representing normal incidence of light.

A schematic diagram of a three-layer structure. It consists of a central rectangular layer with rounded ends, flanked by two thinner rectangular layers. Arrows point from labels $n.5$ to each of the three layers, indicating their refractive index.

A diagram of a microstrip antenna. It consists of a rectangular patch with a grid-like pattern on a substrate. A feed line, represented by a series of small circles, connects the patch to a point labeled 'n.5'.

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Сборочный чертёж ячейки | Лист | | Масса | Масштаб |
| Разраб. | Исабаева Ж. | | | | | | | | 2:1 |
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